

2SB1099

Silicon PNP Darlington Transistor



Uce/Ucb: -100/-100V

Ic / Icm: -8/-12A

β (Ic/Ib): 6000

N: 25W

F: -

Tmax: -



the 2SB1099 is a silicon PNP darlington transistor, Uce = 100V,
applications: integrated diode

Source:

Jaeger electronic catalog 1999